



FORM PTO-1449/A and B (Modified)			APPLICATION NO.: 09/935,776		ATTY. DOCKET NO.: H0498.70154US00	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT			FILING DATE: August 22, 2001		CONFIRMATION NO.: 8935	
			APPLICANT: Charles M. Lieber et al.			
Sheet 1 of 3			GROUP ART UNIT: 2811		EXAMINER: Shouxiang Hu	

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#EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to Applicant.

*a copy of this reference is not provided as it was previously cited by or submitted to the office in a prior application, Serial No. __, filed __, and relied upon for an earlier filing date under 35 U.S.C. 120 (continuation, continuation-in-part, and divisional applications).